

# isc N-Channel MOSFET Transistor

## IXTP05N100M

#### • FEATURES

- Drain Source Voltage-
- : V<sub>DSS</sub>= 1000V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)}$  = 17  $\Omega$  (Max)
- · Fast Switching
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



### APPLICATIONS

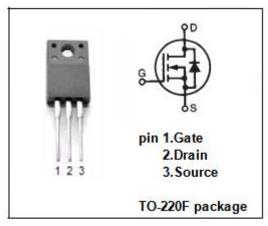
- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- · AC and DC Motor Drives
- · Robotics and Servo Controls

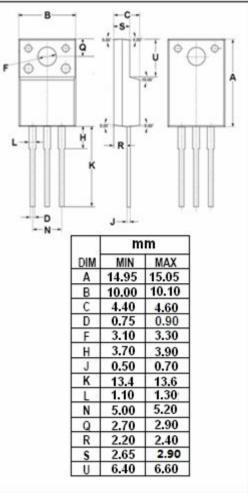
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	1000	٧
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	٧
l <sub>D</sub>	Drain Current-Continuous	Α	
I <sub>DM</sub>	Drain Current-Single Plused	3	Α
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25°C	25	W
Tj	Max. Operating Junction Temperature	-55~150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.23	°C/W







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#### ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP E	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> =250uA	1000			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =250uA	2.5		4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 0.375A			17	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0			±100	nA
IDSS	Zero Gate Voltage Drain Current	V <sub>DS</sub> =1000V; V <sub>GS</sub> = 0 V <sub>DS</sub> =1000V; V <sub>GS</sub> = 0;T <sub>J</sub> =150°C			25 500	μΑ
V <sub>SD</sub>	Diode Forward On-voltage	I <sub>F</sub> = 0.75A;V <sub>GS</sub> = 0			1.5	V

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